

MC74AC253, MC74ACT253

Dual 4-Input Multiplexer with 3-State Outputs

The MC74AC253/74ACT253 is a dual 4-input multiplexer with 3-state outputs. It can select two bits of data from four sources using common select inputs. The outputs may be individually switched to a high impedance state with a HIGH on the respective Output Enable ($\overline{OE}$) inputs, allowing the outputs to interface directly with bus oriented systems.

- Multifunctional Capability
- Noninverting 3-State Outputs
- Outputs Source/Sink 24 mA
- 'ACT253 Has TTL Compatible Inputs
- These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at www.onsemi.com for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.

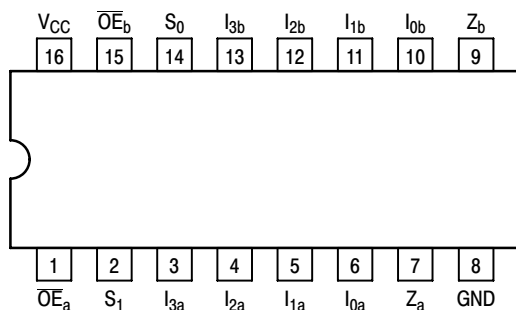


Figure 1. Pinout: 16-Lead Packages Conductors
(Top View)

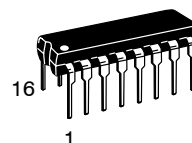
PIN NAME

PIN	FUNCTION
$I_{0a}-I_{3a}$	Side A Data Inputs
$I_{0b}-I_{3b}$	Side B Data Inputs
S_0, S_1	Common Select Inputs
$\overline{OE}_a$	Side A Output Enable Input
$\overline{OE}_b$	Side B Output Enable Input
Z_a, Z_b	3-State Outputs

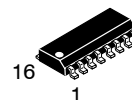


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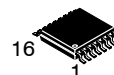
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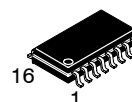
DIP-16
N SUFFIX
CASE 648



SO-16
D SUFFIX
CASE 751B



TSSOP-16
DT SUFFIX
CASE 948F



EIAJ-16
M SUFFIX
CASE 966

ORDERING INFORMATION

Device	Package	Shipping
MC74AC253N	PDIP-16	25 Units/Rail
MC74ACT253N	PDIP-16	25 Units/Rail
MC74AC253D	SOIC-16	48 Units/Rail
MC74ACT253D	SOIC-16	48 Units/Rail
MC74AC253DR2	SOIC-16	2500 Tape & Reel
MC74ACT253DR2	SOIC-16	2500 Tape & Reel
MC74AC253DT	TSSOP-16	96 Units/Rail
MC74ACT253DT	TSSOP-16	96 Units/Rail
MC74AC253DTR2	TSSOP-16	2500 Tape & Reel
MC74ACT253DTR2	TSSOP-16	2500 Tape & Reel
MC74AC253M	EIAJ-16	50 Units/Rail
MC74ACT253M	EIAJ-16	50 Units/Rail
MC74AC253MEL	EIAJ-16	2000 Tape & Reel
MC74ACT253MEL	EIAJ-16	2000 Tape & Reel

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 7 of this data sheet.

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TRUTH TABLE

Select Inputs		Data Inputs				Output Enable	Outputs
S ₀	S ₁	I ₀	I ₁	I ₂	I ₃	OE	Z
X	X	X	X	X	X	H	Z
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
H	L	X	L	X	X	L	L
H	L	X	H	X	X	L	H
L	H	X	X	L	X	L	L
L	H	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Address inputs S₀ and S₁ are common to both sections.

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

FUNCTIONAL DESCRIPTION

The MC74AC253/74ACT253 contains two identical 4-input multiplexers with 3-state outputs. They select two bits from four sources selected by common Select inputs (S₀, S₁). The 4-input multiplexers have individual Output Enable ($\overline{OE}_a$, $\overline{OE}_b$) inputs which, when HIGH, force the outputs to a high impedance (High Z) state. This device is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels

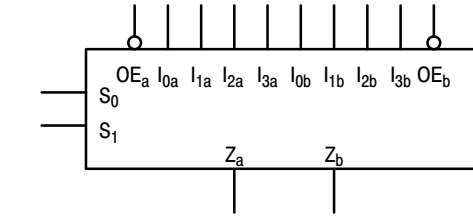


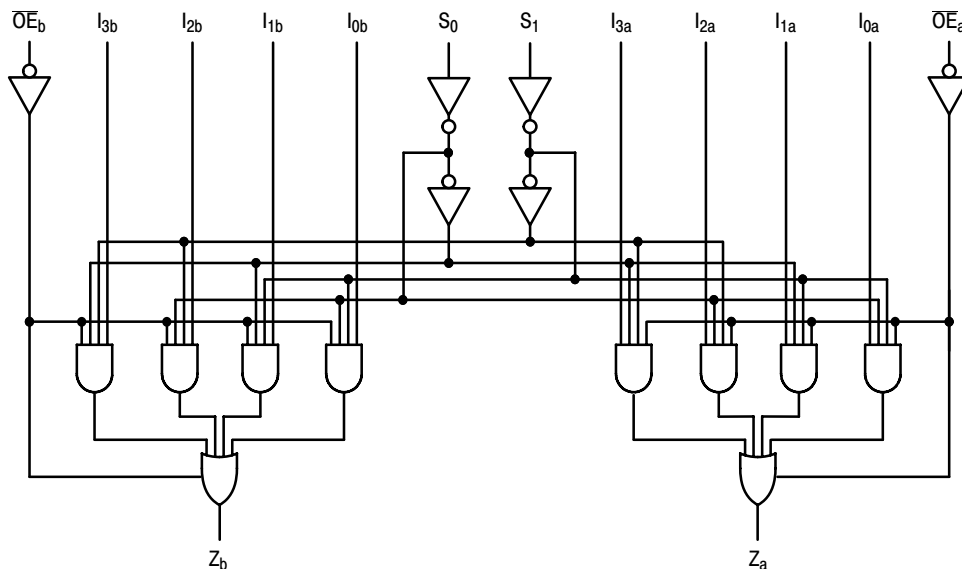
Figure 2. Logic Symbol

supplied to the two select inputs. The logic equations for the outputs are shown:

$$Z_a = \overline{OE}_a \cdot (I_{0a} \cdot \overline{S_1} \cdot \overline{S_0} + I_{1a} \cdot \overline{S_1} \cdot S_0 + I_{2a} \cdot S_1 \cdot \overline{S_0} + I_{3a} \cdot S_1 \cdot S_0)$$

$$Z_b = \overline{OE}_b \cdot (I_{0b} \cdot \overline{S_1} \cdot \overline{S_0} + I_{1b} \cdot \overline{S_1} \cdot S_0 + I_{2b} \cdot S_1 \cdot \overline{S_0} + I_{3b} \cdot S_1 \cdot S_0)$$

If the outputs of 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so that there is no overlap.



NOTE: This diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 3. Logic Diagram

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MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
I_{IN}	DC Input Current, per Pin	± 20	mA
I_{OUT}	DC Output Sink/Source Current, per Pin	± 50	mA
I_{CC}	DC V_{CC} or GND Current per Output Pin	± 50	mA
T_{stg}	Storage Temperature	-65 to +150	°C

*Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	'AC	2.0	5.0	V
		'ACT	4.5	5.0	
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Ref. to GND)	0	-	V_{CC}	V
t_r, t_f	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V_{CC} @ 3.0 V	-	150	ns/V
		V_{CC} @ 4.5 V	-	40	
		V_{CC} @ 5.5 V	-	25	
t_r, t_f	Input Rise and Fall Time (Note 2) 'ACT Devices except Schmitt Inputs	V_{CC} @ 4.5 V	-	10	ns/V
		V_{CC} @ 5.5 V	-	8.0	
T_J	Junction Temperature (PDIP)	-	-	140	°C
T_A	Operating Ambient Temperature Range	-40	25	85	°C
I_{OH}	Output Current – High	-	-	-24	mA
I_{OL}	Output Current – Low	-	-	24	mA

1. V_{IN} from 30% to 70% V_{CC} ; see individual Data Sheets for devices that differ from the typical input rise and fall times.
2. V_{IN} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

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DC CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	74AC		74AC	Unit	Conditions
			T _A = +25°C		T _A = –40°C to +85°C		
			Typ	Guaranteed Limits			
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
		4.5	2.25	3.15	3.15		
		5.5	2.75	3.85	3.85		
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
		4.5	2.25	1.35	1.35		
		5.5	2.75	1.65	1.65		
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I _{OUT} = –50 μA
		4.5	4.49	4.4	4.4		
		5.5	5.49	5.4	5.4		
		3.0	–	2.56	2.46	V	*V _{IN} = V _{IL} or V _{IH} –12 mA I _{OH} –24 mA –24 mA
		4.5	–	3.86	3.76		
		5.5	–	4.86	4.76		
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1		
		5.5	0.001	0.1	0.1		
		3.0	–	0.36	0.44	V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
		4.5	–	0.36	0.44		
		5.5	–	0.36	0.44		
I _{IN}	Maximum Input Leakage Current	5.5	–	±0.1	±1.0	μA	V _I = V _{CC} , GND
I _{OZ}	Maximum 3–State Current	5.5	–	±0.5	±5.0	μA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND
I _{OLD}	†Minimum Dynamic Output Current	5.5	–	–	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}		5.5	–	–	–75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	–	8.0	80	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

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AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

Symbol	Parameter	V _{CC} * (V)	74AC			74AC		Unit	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = –40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation Delay S _n to Z _n	3.3 5.0	2.0 2.0	– –	15.5 11.0	2.0 1.5	17.5 12.5	ns	3–6
t _{PHL}	Propagation Delay S _n to Z _n	3.3 5.0	2.5 2.0	– –	16.0 11.5	2.0 1.5	18.0 13.0	ns	3–6
t _{PLH}	Propagation Delay I _n to Z _n	3.3 5.0	1.5 1.5	– –	14.5 10.0	1.5 1.5	17.0 11.5	ns	3–5
t _{PHL}	Propagation Delay I _n to Z _n	3.3 5.0	2.0 1.5	– –	13.0 9.5	1.5 1.5	15.0 11.0	ns	3–5
t _{PZH}	Output Enable Time	3.3 5.0	1.5 1.5	– –	8.0 6.0	1.0 1.0	8.5 6.5	ns	3–7
t _{PZL}	Output Enable Time	3.3 5.0	1.5 1.5	– –	8.0 6.0	1.0 1.0	9.0 7.0	ns	3–8
t _{PHZ}	Output Disable Time	3.3 5.0	2.0 2.0	– –	9.5 8.0	1.5 1.5	10.0 8.5	ns	3–7
t _{PLZ}	Output Disable Time	3.3 5.0	1.5 1.5	– –	8.0 7.0	1.0 1.0	9.0 7.5	ns	3–8

*Voltage Range 3.3 V is 3.3 V ±0.3 V.

*Voltage Range 5.0 V is 5.0 V ±0.5 V.

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DC CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	74ACT		74ACT		Unit	Conditions
			T _A = +25°C		T _A = –40°C to +85°C			
			Typ	Guaranteed Limits				
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V	
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I _{OUT} = –50 µA	
		4.5 5.5	– –	3.86 4.86	3.76 4.76	V	*V _{IN} = V _{IL} or V _{IH} –24 mA I _{OH} –24 mA	
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I _{OUT} = 50 µA	
		4.5 5.5	– –	0.36 0.36	0.44 0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA I _{OL} 24 mA	
I _{IN}	Maximum Input Leakage Current	5.5	–	±0.1	±1.0	µA	V _I = V _{CC} , GND	
ΔI _{CCT}	Additional Max. I _{CC} /Input	5.5	0.6	–	1.5	mA	V _I = V _{CC} – 2.1 V	
I _{OZ}	Maximum 3–State Current	5.5	–	±0.5	±5.0	µA	V _I (OE) = V _{IL} , V _{IH} V _I = V _{CC} , GND V _O = V _{CC} , GND	
I _{OLD}	†Minimum Dynamic Output Current	5.5	–	–	75	mA	V _{OLD} = 1.65 V Max	
I _{OHD}		5.5	–	–	–75	mA	V _{OHD} = 3.85 V Min	
I _{CC}	Maximum Quiescent Supply Current	5.5	–	8.0	80	µA	V _{IN} = V _{CC} or GND	

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

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AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

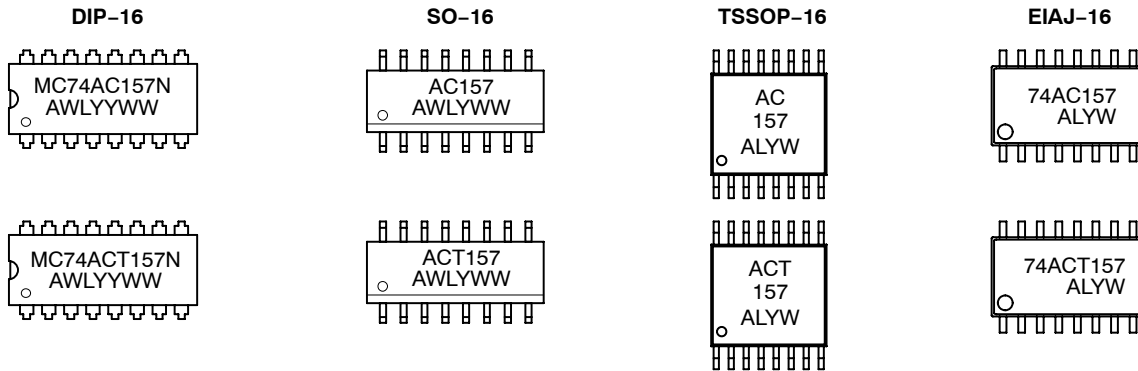
Symbol	Parameter	V _{CC} * (V)	74ACT			74ACT		Unit	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = –40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation Delay S _n to Z _n	5.0	2.0	–	11.5	2.0	13.0	ns	3–6
t _{PHL}	Propagation Delay S _n to Z _n	5.0	3.0	–	13.0	2.5	14.5	ns	3–6
t _{PLH}	Propagation Delay I _n to Z _n	5.0	2.5	–	10.0	2.0	11.0	ns	3–5
t _{PHL}	Propagation Delay I _n to Z _n	5.0	3.5	–	11.0	3.0	12.5	ns	3–5
t _{PZH}	Output Enable Time	5.0	2.0	–	7.5	1.5	8.5	ns	3–7
t _{PZL}	Output Enable Time	5.0	2.0	–	8.0	1.5	9.0	ns	3–8
t _{PHZ}	Output Disable Time	5.0	3.0	–	9.5	2.5	10.0	ns	3–7
t _{PLZ}	Output Disable Time	5.0	2.5	–	7.5	2.0	8.5	ns	3–8

* Voltage Range 5.0 V is 5.0 V ±0.5 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	50	pF	V _{CC} = 5.0 V

MARKING DIAGRAMS

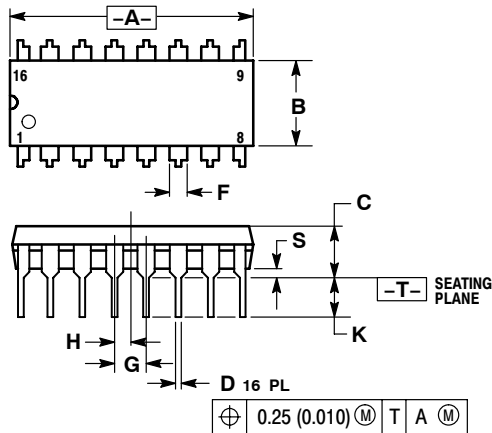


A = Assembly Location
 WL, L = Wafer Lot
 YY, Y = Year
 WW, W = Work Week

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PACKAGE DIMENSIONS

PDIP-16 N SUFFIX 16 PIN PLASTIC DIP PACKAGE CASE 648-08 ISSUE R

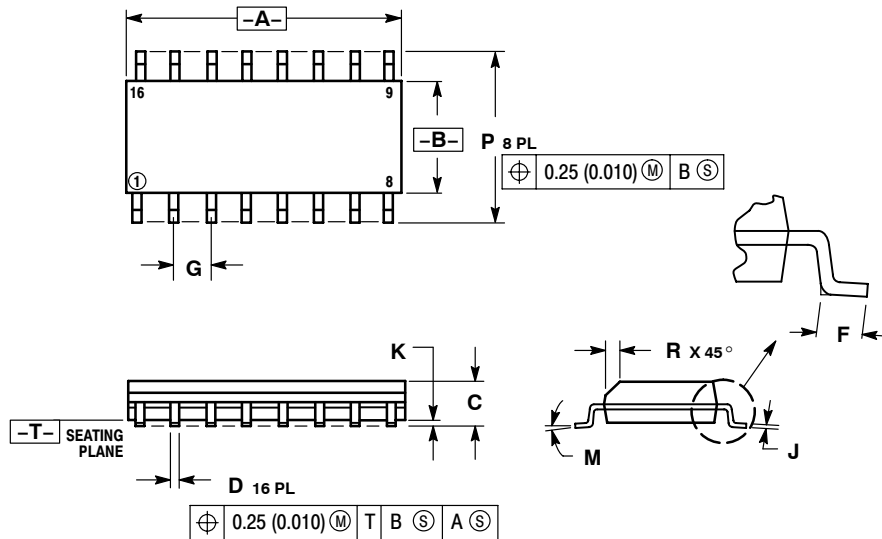


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10°	0°	10°
S	0.020	0.040	0.51	1.01

SO-16 D SUFFIX 16 PIN PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

Notes

Notes

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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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